

Nano-Channeling Acceleration Research @ ASTA

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9: 15 – 9:30 Am, July 24, 2013

Opportunities with Crystal Technology for Accelerators

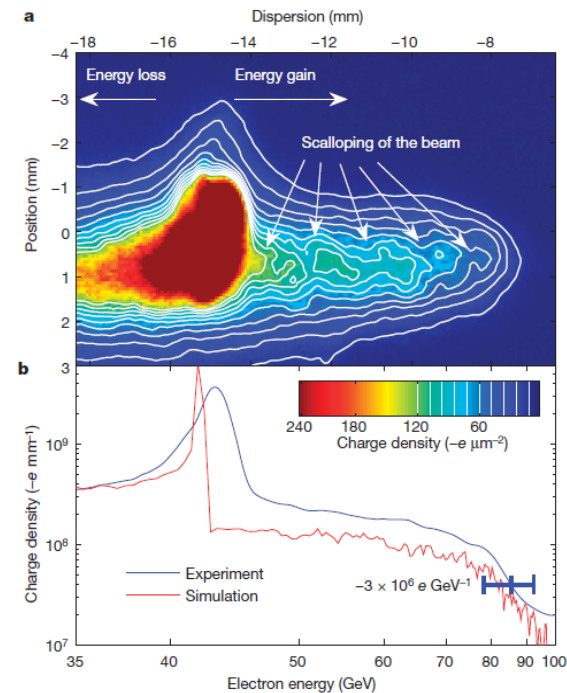
High Gradient Acceleration in Plasma Gas

$$E_0 = \frac{m_e c \omega_p}{e} \approx 100 \left[\frac{\text{GeV}}{m} \right] \cdot \sqrt{n_0 [10^{18} \text{cm}^{-3}]}$$

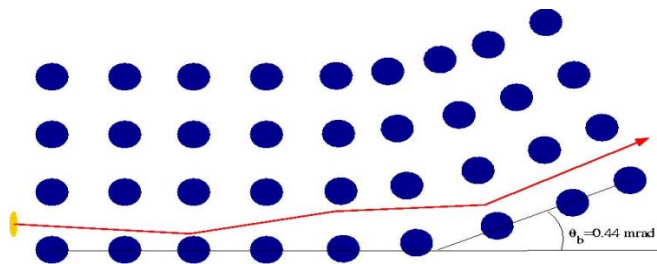
➔ $10^{17} - 10^{18} \text{cm}^{-3} \rightarrow 30 \sim 100 \text{ GeV/m}$

➔ Energy spectrum of the electrons (FFTB @ SLAC) (top) energy spectrum of the electrons in the 35 – 100 GeV range. (head: 43 GeV, tail: 85 GeV) (bottom) projection of the image in (top), shown in blue. The simulated energy spectrum is shown in red.

Nature 445, 741-744 (2007)



Accelerate channeled particles using plasma waves in crystal:

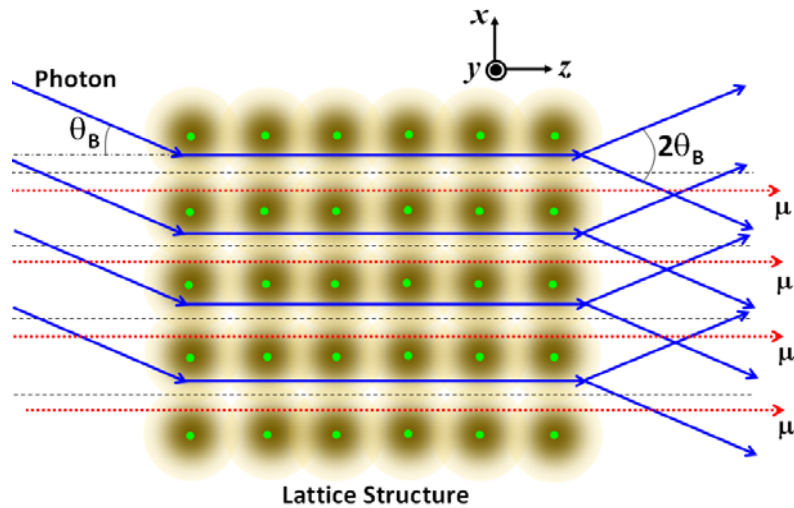


$10^{19} - 10^{22} \text{cm}^{-3} \rightarrow 0.3 \sim 10 \text{ TeV/m}$

- Very stable, can be used for
 - deflection/bending (works)
 - focusing (works)
 - acceleration (if waves excited)

Channeling Acceleration Concepts

• Laser-Driven Acceleration

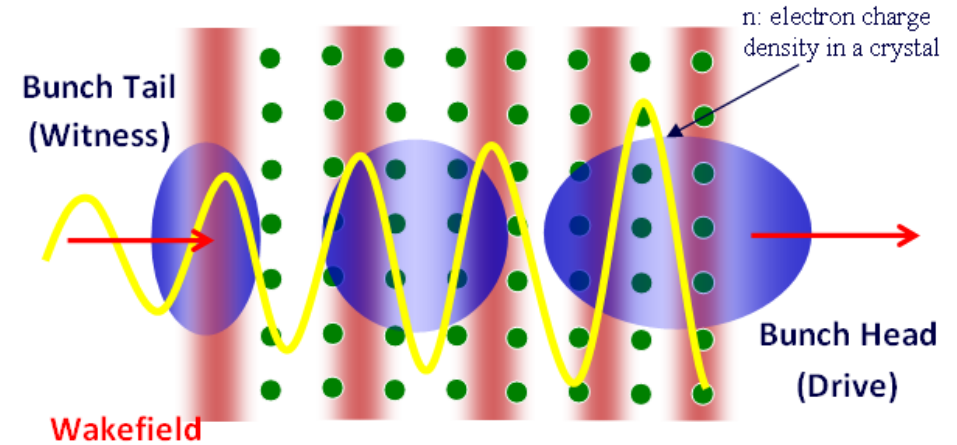


→ T. Tajima and M. Cavenago, Phys. Rev. Lett. 59, 1440 1987

• Particle species: proton/muon

- Driving Source: External Laser Pumping
- Required Laser Specs
 - Diffraction Resonance ($\lambda_v < a$, a : lattice constant)
 - Energy: 40 keV (hard X-ray)
 - $E_l < E_v < E_b$ (E_l : Energy Loss, E_b : Atomic Binding Energy)
 - Power: > 3 GW

• Beam-Driven Acceleration

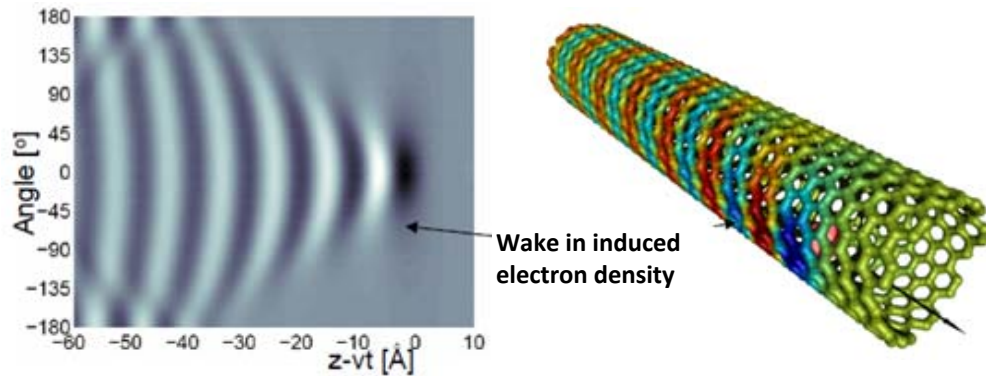


→ P. Chen and R. J. Noble, AIP Conf. Proc. 156, 222 1987

• Particle species: electron/positron

- Driving Source: Particle Bunch (Self-Acceleration)
- Required Beam Specs
 - Bunch Length: $\leq \lambda_p$
 - Spot size: $\geq \lambda_p$

CNTs for Channeling Acceleration



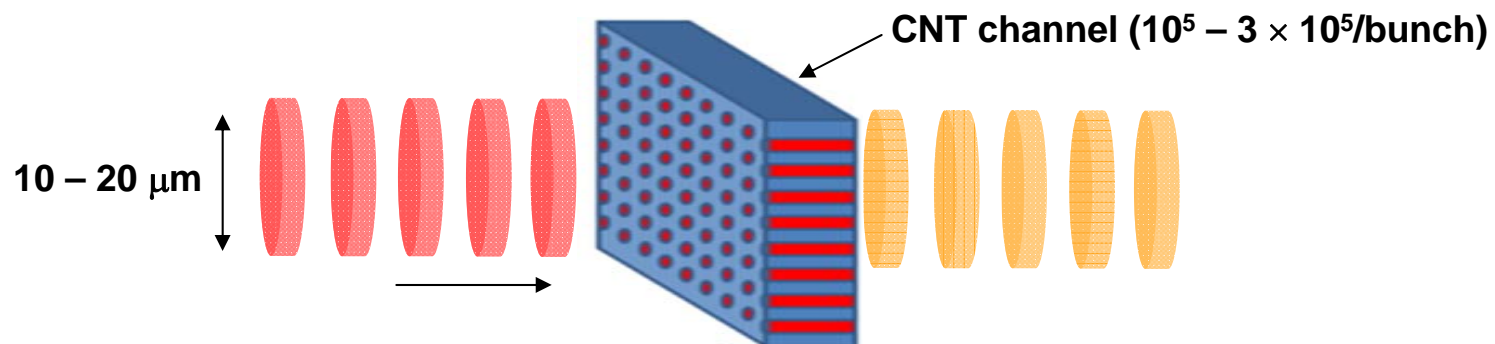
Zoran Miskovic, "Prospects of on channelling through carbon nanotubes", REM talk

Nanotubes for HG Accelerator Application

- [1] B. Newberger, T. Tajima, F. R. Huson, W. Mackay, B. C. Covington, J. R. Payne, Z. G. Zou, N. K. Mahale, and S. Ohnuma, in *Proceedings of the 1989 Particle Accelerator Conference*, Chicago, IL, edited by F. Bennett and J. Kopta IEEE, New York, 1989, p. 630
- [2] L. A. Gevorgyan, K. A. Ispiryan, and R. K. Ispiryan, *Pis'ma Zh. Eksp. Teor. Fiz.* 66, 304 1997, *JETP Lett.* 66, 322 1997
- [3] B. Rau and R. A. Cairns, *Phys. Plasmas* 7, 3031 2000
- [4] S. V. Bulanov, F. F. Kamenets, F. Pegoraro, and A. M. Pukhov, *Phys. Lett. A* 195, 84 1994
- [5] N. Saito and A. Ogata, *Phys. Plasmas* 10, 3358 2003
- [6] M. Murakami, and M. Tanaka, *Appl. Phys. Lett.* 102, 163101 (2013)

• Nanostructure (e.g. CNT) vs Crystal

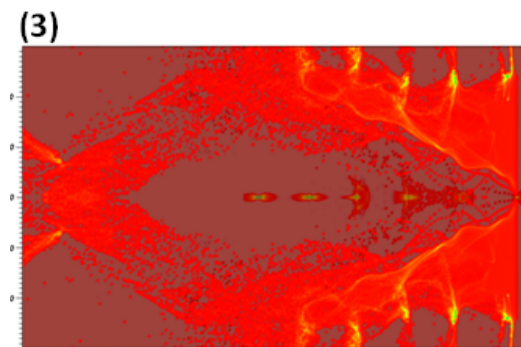
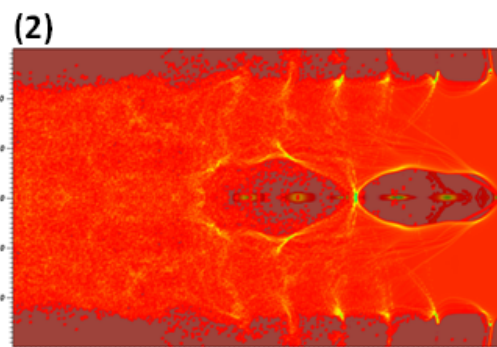
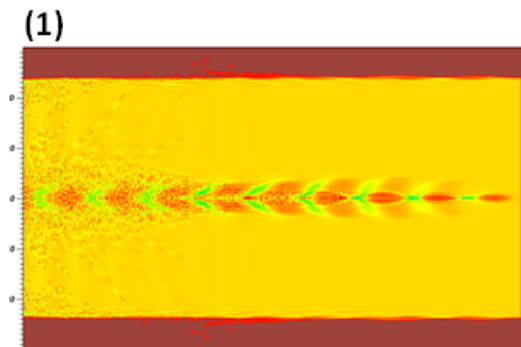
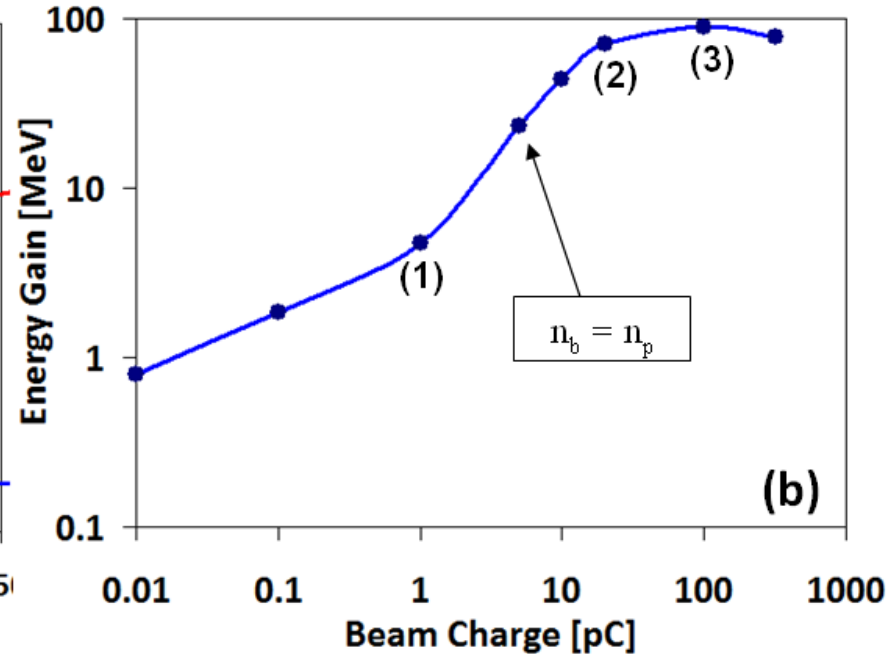
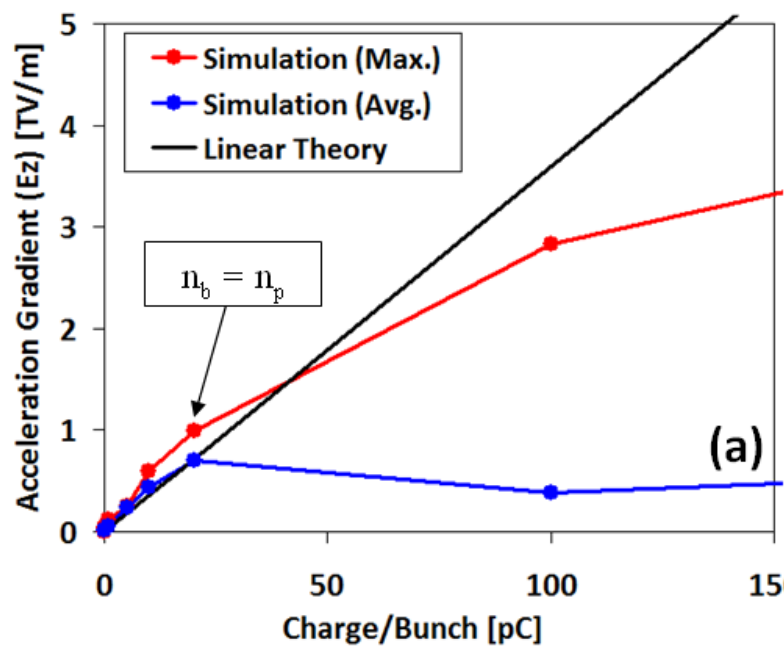
- (1) A size of a channel is readily controllable up to micron. The larger channel can
 - decrease de-channeling rates
 - increase acceptance angles
 - mitigate laser energy/power requirement
- (2) Thermally and mechanically stronger than crystals, steels, or even diamonds (sp^2 bond $>$ sp^3 bond)
 - Higher durability in extremely intense channeling radiation/acceleration



Gain Analysis of Low Density at 50 MeV

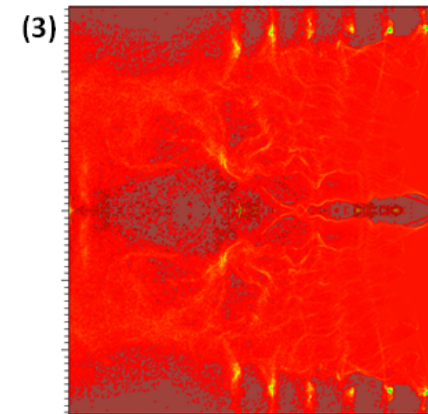
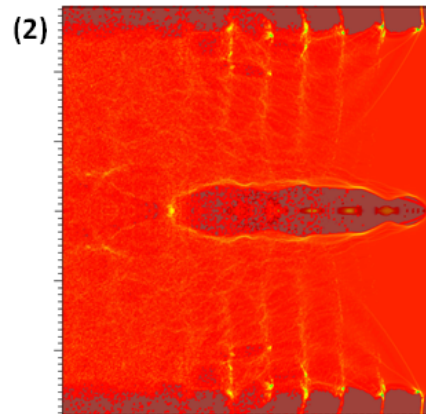
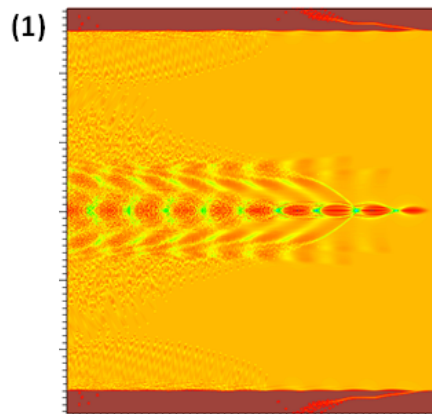
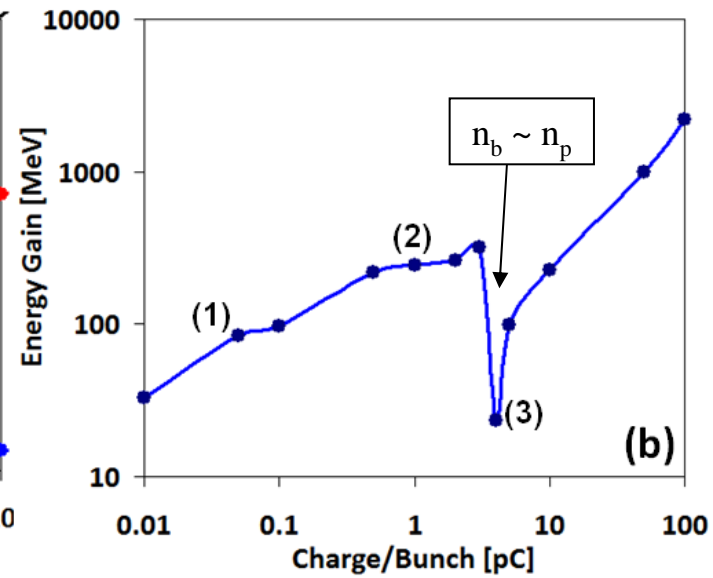
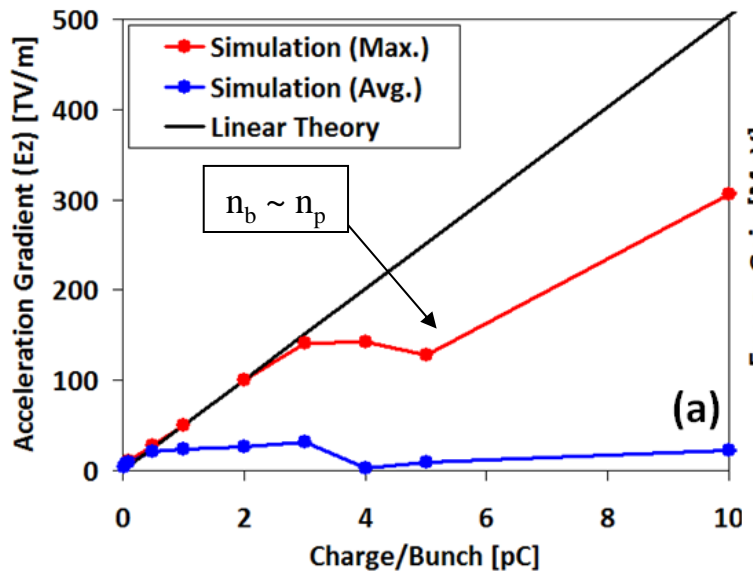
- Beam Energy = 50 MeV
- Bunch-to-Bunch Distance = 10 μm
- # of Bunches = 10
- Bunch Length (RMS) $\sim 2 \mu\text{m}$
- Channel Charge Density = 10^{19} cm^{-3}
- Channel Length = 100 μm

Simulation: Vsim (VORPAL 6.25): "Beam-Driven Wakefield Simulator"

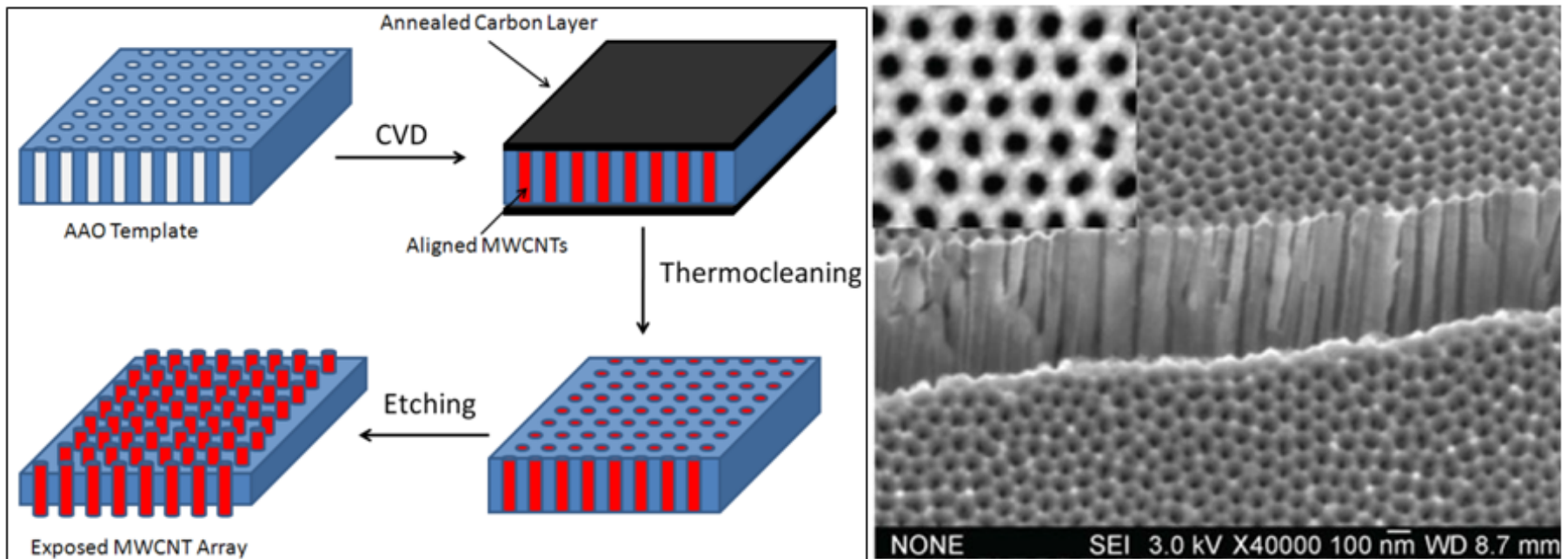


Gain Analysis of High Density at 200 MeV

- Beam Energy = 200 MeV
- Bunch Length (RMS) ~ 27 nm
- Bunch-to-Bunch Distance = $0.267 \mu\text{m}$
- Channel Charge Density = $1.6 \times 10^{22} \text{ cm}^{-3}$
- Channel Length = $2.67 \mu\text{m}$
- # of Bunches = 10



Anodic Aluminum Oxide (AAO) Template Technique (MWCNT)



The AAO film has uniform and straight nano-size channels with a tailored length and diameter. The length, diameter, and density of the as-synthesized CNTs can be uniformly tailored because of the controllability of the pore texture of AAO template.

→ Width: ~ sub-micron

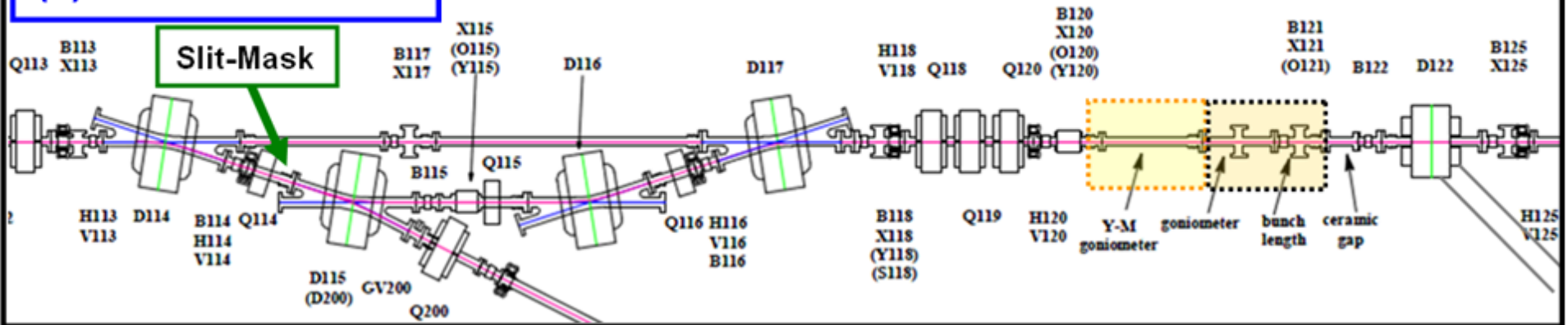
→ Length: 50 ~ 100 micron

Tao Xu of NIU (Dept. of Chemistry) has a full set of hands-on equipment to process growth of MWCNTs on an AAO template.

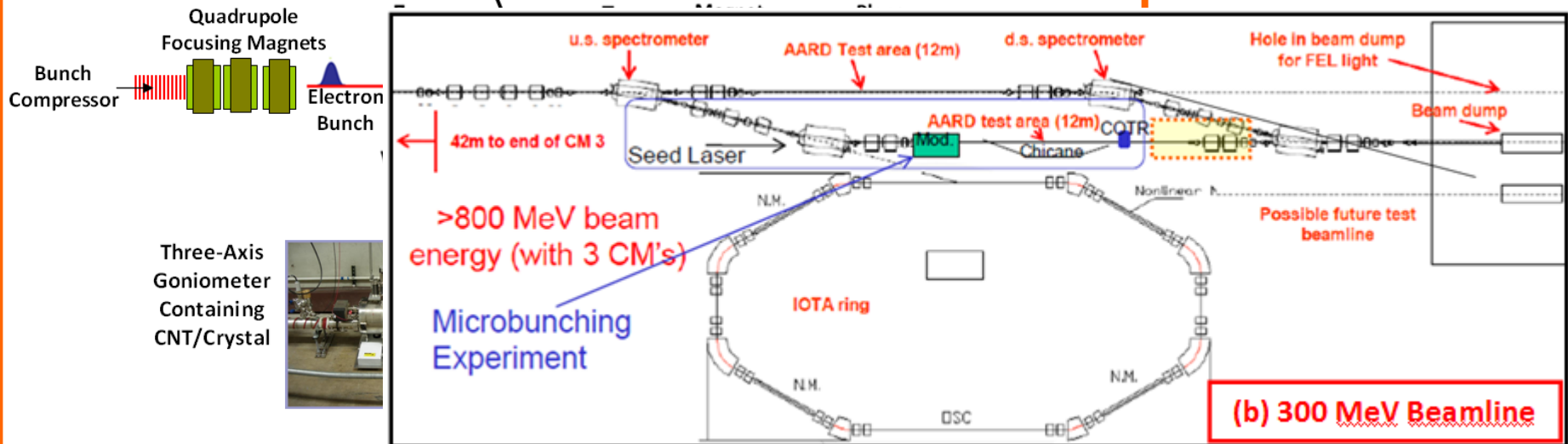
- [1] Masuda H, Hasegawa F, Ono S. J Electrochem Soc, 197, 144: L127–L130
- [2] Martin C R. Chem Mater, 1996, 8: 1739–1746
- [3] Kyotani T, Tsai L F, Tomita A., Chem Mater 1995, 7: 1427–1428
- [4] Kyotani T, Tsai L F, Tomita A., Chem Mater 1996, 8: 2109–2113
- [5] Chen Z, Zhang H G., Soc, 2005, 152: D227 –D231
- [6] Thompson G E., Thin Solid Films, 1997, 297: 192–201

Experiment Layout

(a) 50 MeV Beamline

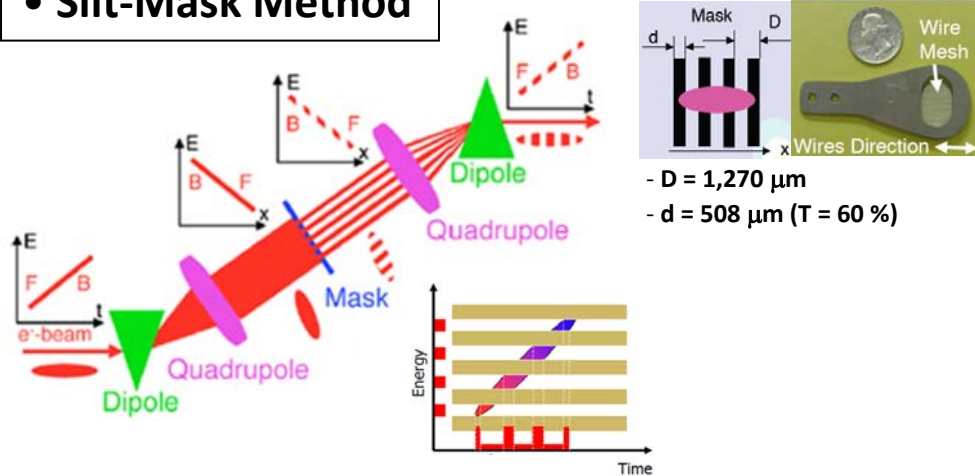


Sample Holder

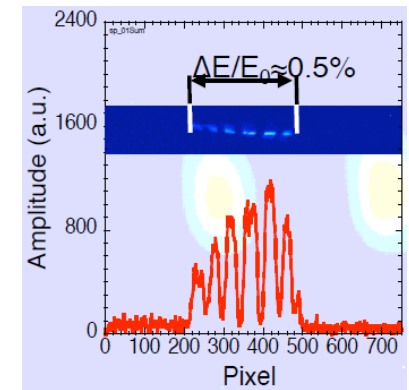


Micro-bunch Generation: Slit-Mask

• Slit-Mask Method

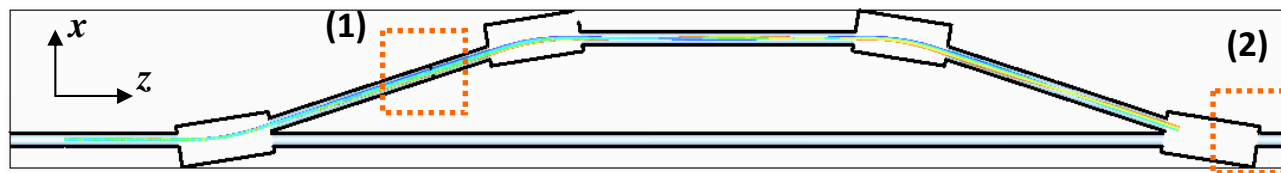
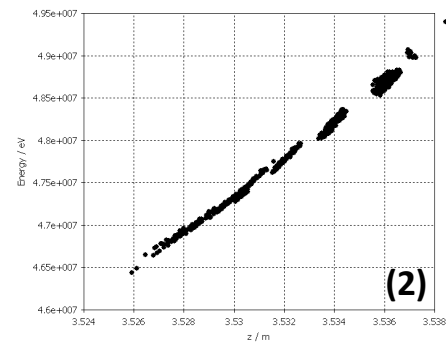
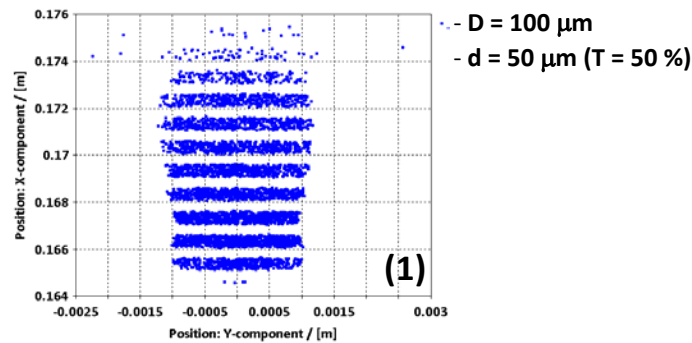


Exp. Parameters @ BNL-ATF



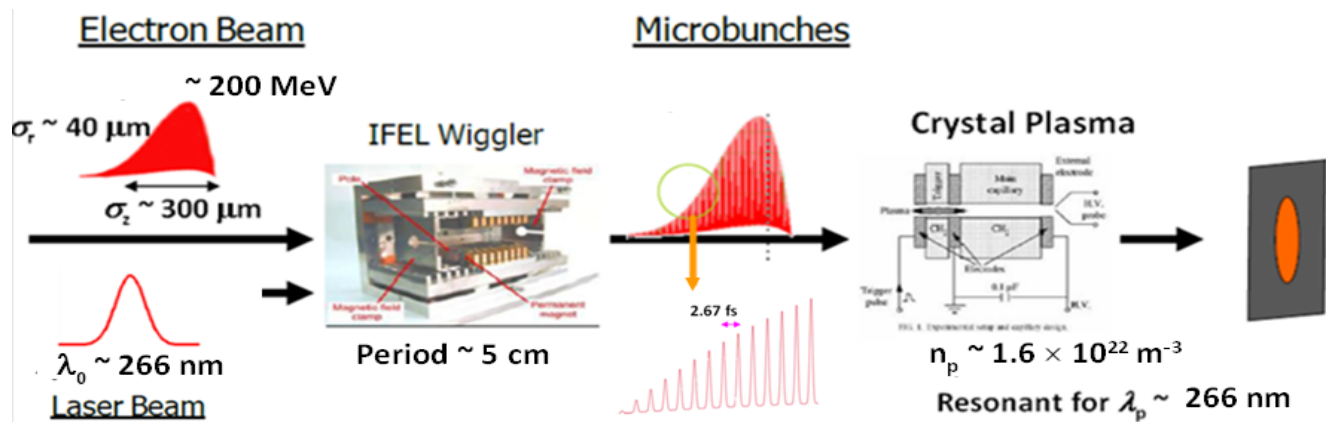
P. Muggli, et. al., PRL 101, 054801 (2008)

• Slit-Mask Microbuncher @ ASTA – 50 MeV Beamline



Micro-bunch Generation Technique (2): IFEL

- IFEL Method



Phase #	Beam Energy (MeV)	Laser Fundamental (nm)	Und. Period (cm), K, n	Microbunching Harmonics (nm)
1a	44.5	800	2.18, 1.2, 3	400,266, 200
1b	44.5	800	2.18, 1.2, 3	100,90,80
2	200	266	5,1.2,1	48, 29,26
	250	800	20, 1.36,1	400,266,200,80
2	500	--	5,1.2,1	---
2	500	266	5,1.2,3	48,29,26
3-HGHG	900	TBD	TBD	
4-SASE	900	--	1.1,0.9,1	3

Beam Parameter/Personnel Involved/Other Opportunity

- Required Beam Parameters (TBO)

- Personnel Involved (TBD)

	Planning	Experiment	Diagnostics	Analysis	Simulation
Y. M. Shin	V	V		V	V
T. Xu		V			
J. C. Thangaraj			V		
V. Shiltsev	V			V	
D. Still		V			
K. A. Carlson		V			
A. Grabenhofer				V	V

Y. M. Shin: Accelerator Physicist

T. Xu: Nano-Fabrication Expert

J.C. Thangaraj: Beam Diagnostics/Microbunching Experimentalist

V. Shiltsev: Crystal R&D Expert

K. A. Carlson/D. Still: Engineering Physicists

A. Grabenhofer: NIU Graduate

- Other Opportunity – Coherent THz Source Development

The diagram shows a 3D model of a nano-lattice structure, which is a periodic array of atoms or molecules. A blue arrow labeled 'T-Ray' indicates the direction of the terahertz radiation. The three phases are:

- Phase-I:** High Aspect Ratio Nanostructure Fabrication using AAO Template/PECVD Technology. This panel shows a scanning electron microscope (SEM) image of a nanostructure and a photograph of a laboratory setup.
- Phase-II:** High Power CW Coherent THz radiation experiment with optimally designed nanostructure using 10–300 MeV beam. This panel shows a schematic of the experimental setup and a photograph of the laboratory.
- Phase-III:** Accelerator-based Medical-THz radiation source development using ultra-compact Field emission EG-Gun and nano-channeling effects. This panel shows a schematic of the experimental setup and a photograph of the laboratory.

- Collaboration with Muonsinc/Jlab (F. Marhauser, G. Flanagan, R. Johnson)

- Why Channeling Acceleration Research is important....??

→ *Because It Offers New Opportunities for Accelerator Technology in Energy Frontier*

- TeV/m Acceleration Gradient → Stable High Energy Gain
- Strong Beam focusing
- High Energy/High Intensity Beam Control → Fast Cooling

- Why ASTA...??

→ *Because it Supplies High Quality Electron Source for Advanced Accelerator R&D*

- High Brightness Beam
- Wide Range of Beam Shaping Flexibility (EEX, Flat Beam Formation, etc)
- Stable Operation

- What Next...??

→ *Plan, Design, Assemble, Install, Test, Analyze....*

- Crystal Channeling Accelerator Can be a Breakthrough for future PeV Collider!

Acknowledgement

- (1) We thank [Dean Still](#) and [Kermit Carlson](#) for Technical Support and for Relocating Goniometers and Electronics from E0/D0 to ASTA
- (2) We thank [Alex Lumpkin](#) for sharing his suggestion on micro-bunching
- (3) We thank [Philippe Piot](#) for helpful discussion and support for the proposal and [Chris Prokop](#) for sharing his ASTA simulation design parameters.